MPSA42 is a Preferred Device

# **High Voltage Transistors**

## **NPN Silicon**

#### **Features**

• Pb-Free Packages are Available\*



Rating	Symbol	Value	Unit
Collector - Emitter Voltage  MPSA43  MPSA42	V <sub>CEO</sub>	200 300	Vdc
Collector – Base Voltage  MPSA43  MPSA42	V <sub>CBO</sub>	200 300	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous	Ic	500	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

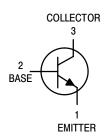
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/mW
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/mW

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



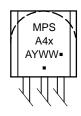
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http://onsemi.com



#### MARKING DIAGRAM





x = 2 or 3

A = Assembly Location

Y = Year WW = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 1) (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	MPSA42 MPSA43	V <sub>(BR)CEO</sub>	300 200	_ _	Vdc
Collector – Base Breakdown Voltage (I <sub>C</sub> = 100 μAdc, I <sub>E</sub> = 0)	MPSA42 MPSA43	V <sub>(BR)CBO</sub>	300 200	- -	Vdc
Emitter – Base Breakdown Voltage $(I_E = 100 \mu Adc, I_C = 0)$		V <sub>(BR)EBO</sub>	6.0	_	Vdc
Collector Cutoff Current $(V_{CB} = 200 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 160 \text{ Vdc}, I_E = 0)$	MPSA42 MPSA43	Ісво	_ _	0.1 0.1	μAdc
Emitter Cutoff Current $(V_{EB} = 6.0 \text{ Vdc}, I_C = 0)$ $(V_{EB} = 4.0 \text{ Vdc}, I_C = 0)$	MPSA42 MPSA43	I <sub>EBO</sub>	_ _	0.1 0.1	μAdc
ON CHARACTERISTICS (Note 1)					•
DC Current Gain $ \begin{aligned} &(I_C=1.0 \text{ mAdc, } V_{CE}=10 \text{ Vdc}) \\ &(I_C=10 \text{ mAdc, } V_{CE}=10 \text{ Vdc}) \\ &(I_C=30 \text{ mAdc, } V_{CE}=10 \text{ Vdc}) \end{aligned} $		h <sub>FE</sub>	25 40 40	- - -	_
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 20 mAdc, I <sub>B</sub> = 2.0 mAdc)	MPSA42 MPSA43	V <sub>CE(sat)</sub>	_ _	0.5 0.4	Vdc
Base–Emitter Saturation Voltage (I <sub>C</sub> = 20 mAdc, I <sub>B</sub> = 2.0 mAdc)		V <sub>BE(sat)</sub>	_	0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS		1	•	•	
Current-Gain - Bandwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)		f <sub>T</sub>	50	_	MHz
Collector–Base Capacitance (V <sub>CB</sub> = 20 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	MPSA42 MPSA43	C <sub>cb</sub>	_ _	3.0 4.0	pF

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MPSA42	TO-92	5000 Units / Box
MPSA42G	TO-92 (Pb-Free)	5000 Units / Box
MPSA42RL1	TO-92	2000 / Tape & Reel
MPSA42RL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA42RLRA	TO-92	5000 Units / Box
MPSA42RLRAG	TO-92 (Pb-Free)	5000 Units / Box
MPSA42RLRF	TO-92	5000 Units / Box
MPSA42RLRFG	TO-92 (Pb-Free)	5000 Units / Box
MPSA42RLRM	TO-92	2000 / Ammo Pack
MPSA42RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA42RLRP	TO-92	2000 / Ammo Pack
MPSA42RLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA42ZL1	TO-92	2000 / Ammo Pack
MPSA42ZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA43	TO-92	5000 Units / Box
MPSA43G	TO-92 (Pb-Free)	5000 Units / Box
MPSA43RLRA	TO-92	2000 / Tape & Reel
MPSA43RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA43ZL1	TO-92	2000 / Ammo Pack
MPSA43ZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

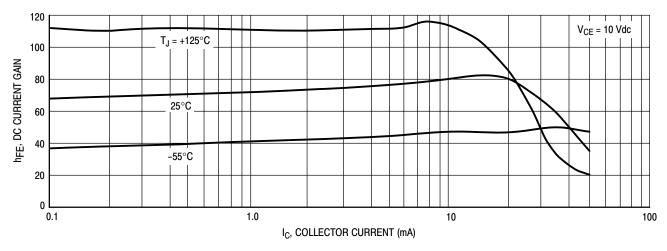


Figure 1. DC Current Gain

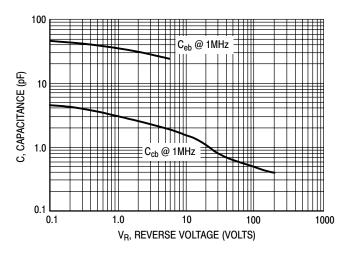


Figure 2. Capacitance

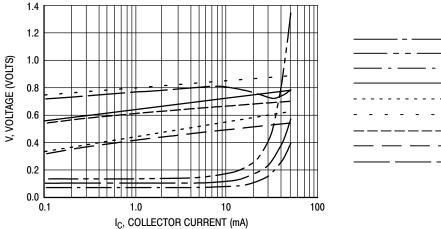
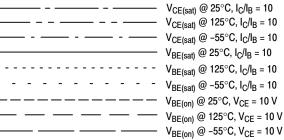
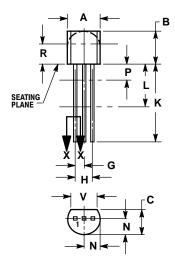


Figure 3. "ON" Voltages



## **PACKAGE DIMENSIONS**

## TO-92 TO-226AA CASE 29-11 **ISSUE AL**





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
v	0 135		3 //3	

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 14:
PIN 1. EMITTER
2. COLLECTOR
3. BASE

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